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SQUID Readout Electronics and Magnetometric **Systems for Practical Applications**

SQUID

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Preface

Time flies! Thirteen years ago, as a research professor at Shanghai Institute of Microsystem and Information Technology (SIMIT), Chinese Academy of Sciences (known as Shanghai Institute of Metallurgy by that time), I was charged with a challenging mission, to start a team on superconducting electronics research. From the institute, it was a quite straightforward decision, as the whole institute had been gradually shifting from materials science research toward electronics and systems. And for myself, it was not so easy to start something new at the age over 40, with a strong background on superconducting materials, some basic knowledge on electronics but little on superconducting electronics. Just when I was wondering how to do that, Prof. P.H. Wu, a member of Chinese Academy of Sciences, a famous professor in the field of superconducting electronics in China, who had worked at Research Center Julich (FZJ) Germany, recommended me Dr. Yi Zhang, a reputable German scientist at FZJ, born in Shanghai, acknowledged globally for his excellent research on the development of high $T_{\rm c}$ radio-frequency superconducting quantum interference devices (high temperature superconducting [HTS] rf SQUIDs), their readout electronics and systems. I contacted FZJ without hesitation, inviting Yi to act as a consultant to our first project on SQUID‐based Magnetocardiography (MCG) system. This request letter opened the door of cooperation between SIMIT and FZJ. To date, our cooperation has developed from a project collaboration between two professors to the establishment of two joint research laboratories and further to a virtual joint research institute. The cooperation also has been extended from

superconductivity to topological insulators and quantum computing.

After some formal procedures, I got the approval of my request letter from Prof. Dr. Joachim Treusch, the former chairman of the board of directors of FZJ, Prof. Dr. Sebastian Schmidt, a current member of the board of directors of FZJ, and Prof. Dr. Andreas Offenhäusser, director of IBN2 (Institute of Bio and Nanoscience, now Institute of Biological Information Processing), which Yi belonged to. Besides the support from the top management, the involvement of Prof. Dr. Hans‐Joachim Krause, team leader of magnetic sensors in IBN2, was another important step for our successful cooperation.

Our joint research on dc SQUID started from the development of asymmetrical SQUID characteristics, in an attempt to simply SQUID readout and system design. The adventure was full of excitement and frustration. Early in the morning, we sat together, planning the work of the day, late in the evening, we summarized our results from the notes we made during the day, sometimes exciting progress, sometimes frustrating results, and sometimes confusing results which we could not describe easily. I still remember how excited we were when we first observed the asymmetrical flux‐current characteristics of a SQUID on the oscilloscope, and I remembered as well how much we were frustrated when we learnt that the desired asymmetrical characteristics did not lead to the lower noise we had sought for so long. The notes piled up day after day, getting thicker and thicker, we called them "Rabe's Diary." After numerous discussions back and forth, we succeeded in interpreting our results, which led to our first joint publication and our joint patent on the so‐called "SQUID Bootstrap Circuit," and to many other joint publications in the following 10 more years.

The SQUID research was more difficult than we first thought because setting up SQUID systems for applications requires the involvement of people from several different disciplines. A complete understanding for SQUID systems needs comprehensive knowledge not only in quantum physics and low‐temperature physics but also in material science and electronics engineering. In fact, electrical or electronics engineers are always needed for system development. Therefore, it is very important to establish a common language that is easily accessible for all people. That was how we got the idea to write this book.

Yi Zhang contributed most to writing of this book, with his experience in SQUID research for 34  years, including more than 10 years of joint research with SIMIT. We have aimed to write this book in a way that is easily understandable for engineers and students, in order to overcome the formidable barrier of "quantum" physics. In this book, e.g. dc SQUIDs are simply treated as resistor‐like elements, which are modulated by the magnetic flux. We hope that this book will be appreciated by all people interested in developing and working with SQUIDs and SQUID systems. By inviting engineers into the SQUID "family," we will have a better chance to transform SQUID from a laboratory toy to an enabling technology that will eventually shape our life.

This book is largely a documentation of the joint achievements accomplished in the cooperation between SIMIT and FZJ in the field of superconducting electronics. We believe that the ongoing collaboration between the two parties will continue to grow, and the cooperation will bring more achievements not only in the field of superconducting electronics but also in other fields in the future.

November 2019.

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1 Introduction

1.1 Motivation

Superconducting QUantum Interference Devices (SQUIDs) are well known because they are the most sensitive sensors for measuring magnetic flux. In magnetometry, a SQUID with a field‐to‐flux transformer circuit (converter) construct is a magnetometer with high field sensitivity in the range of fT/√Hz (one millionth of the earth's magnetic field). Therefore, the study of SQUID systems has never stopped.

Many books and reviews have elaborated on the SQUID principle and SQUID magnetometric systems as well as SQUID applications, e.g. "Superconductor Applications: SQUIDs and Machines" edited by B. B. Schwartz and S. Foner [1], "Physics and Applications of the Josephson Effect" edited by A. Barone and G. Paterno [2], and the NATO proceedings "SQUID Sensors: Fundamentals, Fabrication and Applications" edited by H. Weinstock [3]. In particular, "The SQUID Handbook," edited in 2004 by John Clarke and Alex I. Braginski comprehensively summarizes SQUID's theory and practice since SQUIDs have been discovered $[4]$. Hence, this book has become the new "bible" for researchers in the field. Furthermore, the review of "SQUID Magnetometers for Low‐Frequency Applications" by Tapani Ryhänen et al. presented a novel formulation for SQUID operation and SQUID magnetometers for low‐frequency applications, taking into account the coupling circuits and electronics $[5]$.

Structurally, a direct current (dc) SQUID is a superconducting ring interrupted with two Josephson junctions. Predicatively, SQUIDs have very rich physical meanings, e.g. the Aharonov–Bohm effect, flux quantization, Meissner effect, Bardeen–Cooper–Schrieffer (BCS) theory, and the Josephson tunnel effect. However, starting from the view of electronic circuits, our first question is on what a dc SQUID is. In magnetometry, a dc SQUID should be regarded as a resistor‐like element where its dynamic resistance is modulated by the flux Φ threading the SQUID's loop. In the readout technique, the dynamic resistance of the SQUID, $R_{\rm d}(\Phi) = \partial\mathit{V}/\partial\mathit{I}$, i.e. the derivative of the voltage with respect to current, is the fundamental readout quantity, which is embodied in the current–voltage $(I-V)$ characteristics of the SQUID. Here, the changing $I-V$ characteristics are limited by two curves at the integer (upper limit) and half‐integer (lower limit) of the flux quantum Φ_0 , which reflect the quantity of magnetic flux in the SQUID loop. There is already abundant "know‐how" to read out a resistor R. For example, one can measure a voltage V across R with a constant current flowing through R or measure a current I through R when a constant voltage V is connected to R in parallel. A dc SQUID can either be operated at constant current by measuring the voltage across it (called current bias mode) or at constant voltage by measuring the current through it (called voltage bias mode). In either bias mode, only the SQUID's V(Φ) or $I(\Phi)$ characteristics emerge. Similar to the change in $I-V$ characteristics with the flux, $V(\Phi)$ and $I(\Phi)$ are also modulated by Φ. In brief, the essence of all three SQUID characteristics is recording the SQUID's dynamic resistance changes, $R_{\rm d}(\Phi).$

Generally, a SQUID system consists of the SQUID sensor and its readout electronics. The small SQUID signal leads to difficulty in reading out the SQUID's signal without additional noise contributions from the readout technique. Conventionally, one hopes to suppress such noise

contribution below the intrinsic SQUID noise $\delta \Phi_{\rm s}$. In other words, the measured system noise almost reaches $\delta \Phi_{\rm s} .$

The main noise source in readout electronics is the preamplifier, which possesses two independent noise sources: the voltage noise $\,V_{\rm n}$ and the current noise $I_{\rm n}.$ Both of these noise sources are innate to the amplifier chip and cannot be changed. In order to compare these two noise contributions in a SQUID system, both types of electronic noise should be translated into a flux noise, $\delta \Phi_{\rm e}$, in units of Φ_0 /√Hz with SQUID's transfer coefficient of ∂*V*/∂Φ or ∂*I*/∂Φ. In fact, the original SQUID parameters including the transfer coefficients are also innate to the particular SQUID and cannot be changed. However, the SQUID's apparent parameters at the input terminal of the preamplifier can be modified. Over the past half century, people have developed different readout schemes, where the electronic noise $\delta \Phi_{\rm e}$ is suppressed by increasing the apparent transfer coefficients once a preamplifier is selected. Indeed, the modification of the apparent parameters is the main thread running through the book. Here, we will change the perspective to discuss the optimization of the SQUID system noise, i.e. how to match the SQUID parameters with the readout electronics.

According to the type of superconducting material used, SQUIDs can be divided into two groups: the low‐ temperature superconducting (LTS) SQUID, also called low‐ $T_{\rm c}$ SQUID, usually operated at 4.2 K (liquid helium temperature); and the high‐temperature superconducting (HTS) SQUID, also called high- $T_{\rm c}$ SQUID, usually operated at 77  K (the liquid nitrogen temperature). The LTS material is typically niobium and HTS material is yttrium barium copper oxide (YB₂Cu₃O_{7−x}).

However, according to the working principles, the dc SQUID mentioned above is completely different from the radio frequency (rf) SQUID, which is a superconducting ring interrupted with only one junction. To read the signal from an rf SQUID, it is inductively coupled to an rf tank circuit, which connects to the readout electronics.

In this book, LTS (low- $T_{\rm c}$) dc SQUID and HTS (high- $T_{\rm c}$) rf SQUID systems, which are often used in magnetometry, will be highlighted. We will share our experiences and lessons, mostly from our own works, with readers, college students, and graduates in physics and engineering who have an interest in SQUID techniques, e.g. how to set up a simple SQUID system for themselves.

1.2 Contents of the Chapters

The book is organized into 12 chapters, where most of the content (from $Chapters 2–11$) is about the dc SQUIDs, and</u> only the last chapter is related to rf SQUIDs. However, the dc SQUID bias reversal scheme $[6]$, the 1/*f* noise study $[7,8]$, and the special readout scheme for the nano-SQUID [9,10] are not included.

[Chapter 1](#page-23-0): This chapter is devoted to our motivation above and the subsequent chapter contents – why did we write this book, and what is it about?

Chapter 2: Because the Josephson junction (II) is the key element of SQUIDs, Josephson's equations should be first introduced. Then, JJs are analyzed with the resistively and capacitively shunted junction (RCSJ) model, thus introducing two important parameters: the Stewart– McCumber parameter $\beta_{\rm c}$ and the thermal rounding parameter Γ. To observe the features of JJs, one often uses the I–V characteristics, where the hysteresis behavior depends on the values of both $\beta_{\rm c}$ and Γ. Actually, the $I\text{-}V$

characteristics describe the changing dynamic resistances $R_{\rm d}$ of the JJ, i.e. $R_{\rm d}$ = ∂ $V\!\!/ \partial I$. It was experimentally verified that the value of $R_{\rm d}$ depends not only on the junction shunt resistor $R_{\rm J}$ but also on the junction critical current $I_{\rm c}$. Generally, JJs without hysteresis are suitable for SQUID operation. In fact, one habitually transforms the parameters $\beta_{\rm c}$ and Γ of the JJ into SQUID operation.

Chapter 3: For readout electronics, the dc SQUID is regarded as dynamic resistance $R_{\mathrm{d}}(\Phi)$ modulated by the flux threading into the SQUID loop. The SQUID's I–V characteristics can be divided into three regions, and the SQUID is operated in the flux‐modulated region (II). In fact, the behavior of $R_{\rm d}(\Phi)$ is embodied in a SQUID's $I\text{-}V$ characteristics. To measure a resistance $R_{\rm d}$, one can impress a known current (current bias) into a SQUID and observe the voltage across the SQUID's dynamic resistance $R_{\rm d}$. Alternatively, one can apply a constant voltage to the SQUID (voltage bias) and measure the current passing through $R_{\rm d}$. Owing to the small $R_{\rm d} \approx 10\,\Omega$ of the SQUID, an ideal current bias mode for SQUID operation can easily be realized. In contrast, an ideal voltage bias mode can hardly be achieved, as will be shown in the course of the chapter.

Chapter 4: Almost all SQUID readout electronics developed over the past half century have a common feature: they establish a so-called flux-locked loop (FLL) to realize linearization of the output voltage $V_{\text{out}}(\Phi)$ of the readout electronics; i.e. V_{out} is proportional to the flux change Φ . In this chapter, the principle and realization of the FLL are explained. It is a nulling method where a compensation flux always follows the measured flux, thus resulting in a total flux change of zero in the SQUID loop. In the FLL, the concept of the working point W comes up, and the "locked" and "unlocked" cases are discussed. In the FLL, a small

flux change $\Delta\Phi$ near the working point W appears transiently, and a counter flux $-\Delta\Phi$ immediately compensates it so that the SQUID is continuously operated at a constant flux state. Therefore, the SQUID's $R_{\mathrm{d}}(\Phi)$ near W can be expressed as $R_{\rm d}(\Phi) = R_{\rm d} + \Delta R_{\rm d}$, where $R_{\rm d}$ is considered a fixed resistance and $\Delta R_{\rm d}$ is a minor change with flux. According to the SQUID's bias modes, $\Delta R_{\rm d}$ is translated into the readout quantity ΔV (or ΔI). For example, in practice, a current‐biased SQUID can be regarded as a voltage source, $\Delta V = \Delta \Phi \times (\partial V / \partial \Phi)$, connecting to the fixed $R_{\rm d}$ in series (which seems to be the internal resistance of the voltage source), where $(\partial V/\partial \Phi)$ is the SQUID's flux‐to‐voltage transfer coefficient at the working point W. The description of the SQUID by means of a differential dynamic resistance is a new model concept.

Chapter 5: In the case of a direct readout scheme (DRS) where the SQUID directly connects to a preamplifier, the electronics noise $\delta\Phi_{\rm e}$ is usually much larger than the SQUID intrinsic noise $\delta\Phi_{\rm s}$. Two types of preamplifiers, commercial op‐amps (e.g. AD797 from Analog Devices Inc. or LT1028 from Linear Technology Corp.) and parallel‐ connected bipolar pair transistors (PCBTs) (e.g. 3  ×  SSM2210 or 3 × SSM2220 from Analog Devices Inc.), are the most commonly used. Here, the noise characteristics, $V_{\rm n}$ and $I_{\rm n}$, of these two types of preamplifiers are measured separately. Nevertheless, a DRS exhibits several advantages; e.g. the SQUID's original parameters can be directly determined, and the noise contributions from both sides, $\delta\Phi_{\rm e}$ and $\delta\Phi_{\rm s}$, can be separately analyzed. Especially, the SQUID's transfer coefficient ∂V/∂Φ (∂I/∂Φ) at the working point W plays two important roles: (i) it bridges different kinds of noise sources, thus unifying all noise in units of $\Phi_0/\sqrt{\text{Hz}}$, as the SQUID is a flux sensor; and (ii) a

large transfer coefficient is beneficial for reducing $\delta\Phi_{\rm e}$. In fact, it was experimentally confirmed that the noise contribution of $\delta\Phi_{\rm e}$ does not depend on the SQUID's bias modes. Furthermore, for strongly damped SQUIDs, $\delta \Phi_{\rm e}$ in DRS dominates the system noise $\delta \Phi_{\rm svs.}$

Chapter 6: In a SQUID magnetometric system, one strives for a high magnetic field sensitivity $\delta B_{\rm sys}$, which involves two aspects: a field‐to‐flux transformer circuit (converter) and an ordinary SQUID system with an FLL. The former converts a magnetic field signal B into a flux Φ threading the SQUID loop, while the latter reads out the picked-up Φ . In Section 6.1, the requirements of the converter are discussed. In **Section 6.2**, we show that the SQUID system is characterized by three dimensionless parameters, $\beta_{\rm c}$, Γ, and $\beta_{\rm L}.$ Note that the definitions of $\beta_{\rm c}$ and Γ for only a single II are given in Chapter 2. During SQUID operation, both parameters must be given a new connotation. Four SQUIDs with different $\beta_{\rm c}$ values were characterized. Here, a reasonable interpretation of the observed absence of hysteresis in the SQUID's *I-V* characteristics at high $\beta_{\rm c}$ is given. For SQUID operation, the dimensionless parameter $\beta_{\rm L}$ particularly describes the modulation depth of the SQUID. Importantly, $\beta_{\rm L} \approx 1$ imposes a design condition on the product $L_\mathrm{s} I_\mathrm{c}$ – namely, all electrically readable values of SQUID parameters increase with increase in the SQUID's nominal $\beta_{\rm c}$.

Chapter 7: The flux modulation scheme (FMS) was first introduced to the SQUID readout in 1968 and quickly became the standard readout technique for current‐biased SQUIDs. To date, FMS electronics have been the most extensively used. The basic idea of the FMS is to perform an up‐conversion of the SQUID's voltage swing at the input terminal of the preamplifier with a step‐up transformer,